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Ultrafast Rectifier, 30 A FRED Pt[®]



PRIMARY CHARACTERISTICS					
I _{F(AV)}	30 A				
V _R	1200 V				
V _F at I _F at 125 °C	2.05 V				
t _{rr}	49 ns				
T _J max.	175 °C				
Package	2L TO-220AC				
Circuit configuration	Single				

FEATURES

- · Ultrafast and soft recovery
- Optimized forward voltage drop
- 175 °C maximum operating junction temperature
- Polyimide passivation
- Rugged design
- · Good thermal performance
- Meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Ultrafast recovery rectifiers designed with optimized performance of forward voltage drop, recovery time, and soft recovery. Polyimide passivated, planar structure, and the platinum doped life time control guarantee, ruggedness, reliability characteristics, and solid value proposition for efficiency and thermal performance.

These devices are intended for use in boost stage in the AC/DC section of SMPS, high frequency output rectification of battery charger, inverters for solar inverters, or as freewheeling diodes in motor drive.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage	V _{RRM}		1200	V			
Average rectified forward current	I _{F(AV)}	T _C = 100 °C, D = 0.50	30	A			
Repetitive peak forward current	I _{FRM}		60	A			
Non-repetitive peak surge current	I _{FSM}	T_{C} = 25 °C, t_{p} = 10 ms, sine wave	240	A			
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 500 μA	1200	-	-		
Forward voltage	VF	I _F = 30 A	-	2.15	2.68	V	
	٧F	$I_F = 30 \text{ A}, T_J = 125 \text{ °C}$	-	2.05	2.45		
	I _R	$V_R = V_R$ rated	-	-	145		
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	320	μA	
Junction capacitance	CT	V _R = 200 V	-	29	-	pF	
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH	

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 10$	00 A/µs, V _R = 30 V	-	49	-		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	220	-	ns	
		T _J = 125 °C		-	356	-		
Peak recovery current	I _{RRM}	T _J = 25 °C	I _F = 30 A dI _F /dt = 100 A/μs V _B = 390 V	-	8.2	-	A	
		T _J = 125 °C		-	13.3	-		
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	900	-	nC	
		T _J = 125 °C		-	2388	-		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Thermal resistance, junction to case	R _{thJC}		-	-	0.8		
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	54	°C/W	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	-	0.4		
Weight			-	2.0	-	g	
Weight			-	0.07	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C	
Marking device		Case style: 2L TO-220AC	30ETU12				

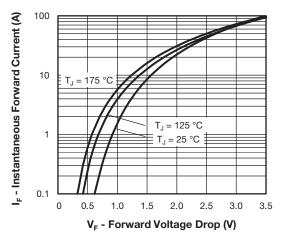


Fig. 1 - Typical Forward Voltage Drop Characteristics

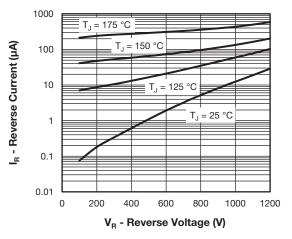


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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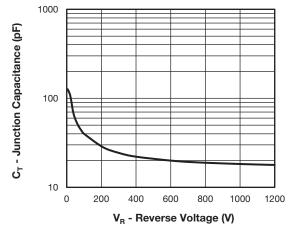


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

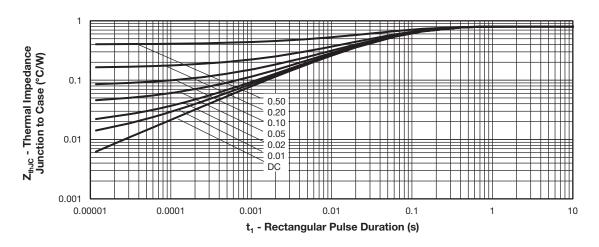
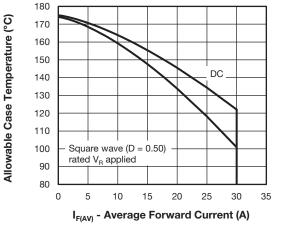
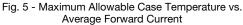


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Average Power Loss (W)





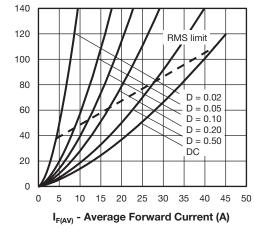


Fig. 6 - Forward Power Loss Characteristics

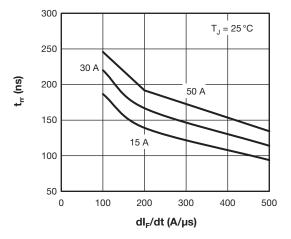
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Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

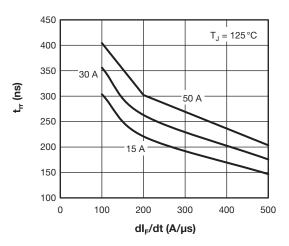


Fig. 8 - Typical Reverse Recovery Time vs. dI_F/dt

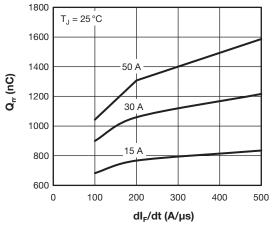


Fig. 9 - Typical Stored Charge vs. dl_F/dt

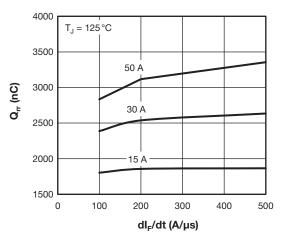


Fig. 10 - Typical Stored Charge vs. dl_F/dt

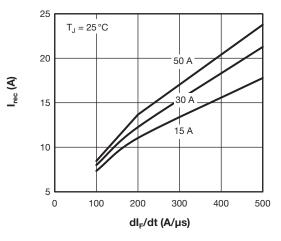


Fig. 11 - Typical Reverse Current vs. dl_F/dt

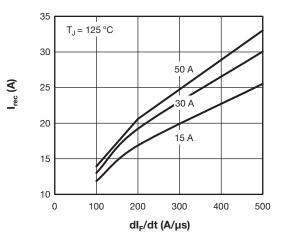


Fig. 12 - Typical Reverse Current vs. dI_F/dt

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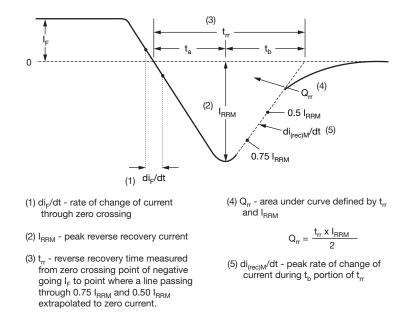


Fig. 13 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

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Device code	VS-	30	Е	т	U	12	-M3	
		2	3	4	5	6	7	
	1	- Visl	nay Sen	nicondu	ctors pro	oduct		
	2	- Cur	rent rati	ng 30 =	30 A			
	3	- E=	E = single diode					
	4	- Pac	Package: T = TO-220AC					
	5	- U =	U = ultrafast recovery					
	6	- Vol	Voltage rating (12 = 1200 V)					
	7	- Env	Environmental digit:					
		-M3	s = halog	gen-free	, RoHS	-complia	ant, and	

ORDERING INFORMATION (Example)								
PREFERRED P/N	N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-30ETU12-M3	50	1000	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?96156</u>					
Part marking information	www.vishay.com/doc?95391				

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